MPPS™ Miniature Package Power Solutions 80V NPN LOW SATURATION TRANSISTOR

SUMMARY

NPN — V_{CEO} = 80V; R_{SAT} = 68m Ω ; I_{C} = 3.5A

DESCRIPTION

Packaged in the new innovative 2mm x 2mm MLP (Micro Leaded Package) outline, these new 4th generation low saturation dual PNP transistors offer extremely low on state losses making them ideal for use in DC-DC circuits and various driving and power management functions.

Additionally users gain several other key benefits:

Performance capability equivalent to much larger packages Improved circuit efficiency & power levels PCB area and device placement savings Lower Package Height (0.9mm nom) Reduced component count



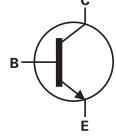
MLP322

FEATURES

- Low Equivalent On Resistance
- Extremely Low Saturation Voltage (185mV max @1A)
- h_{FF} specified up to 5A
- I_C=-3.5A Continuous Collector Current
- 2mm x 2mm MLP

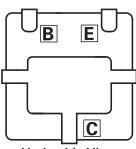
APPLICATIONS

- DC DC Converters
- DC DC Modules
- Power switches
- Motor control



ORDERING INFORMATION

DEVICE	REEL SIZE	TAPE WIDTH	QUANTITY PER REEL					
ZXTEM322TA	7″	8mm	3000					
ZXTEM322TC	13″	8mm	10000					



Underside View

DEVICE MARKING

SE



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	LIMIT	UNIT
Collector-Base Voltage	V _{CBO}	100	V
Collector-Emitter Voltage	V _{CEO}	80	V
Emitter-Base Voltage	V _{EBO}	7.5	V
Peak Pulse Current	I _{CM}	5	А
Continuous Collector Current ^(a)	I _C	3.5	А
Base Current	I _B	1000	mA
Power Dissipation at TA=25°C ^(a) Linear Derating Factor	P _D	1.5 12	W mW/°C
Power Dissipation at TA=25°C (b) Linear Derating Factor	P _D	2.45 19.6	W mW/°C
Power Dissipation at TA=25°C ^(d) Linear Derating Factor	P _D	1 8	W mW/°C
Power Dissipation at TA=25°C ^(e) Linear Derating Factor	P _D	3 24	W mW/°C
Operating & Storage Temperature Range	T _j :T _{stg}	-55 to +150	°C
Junction Temperature	Tj	150	°C

THERMAL RESISTANCE

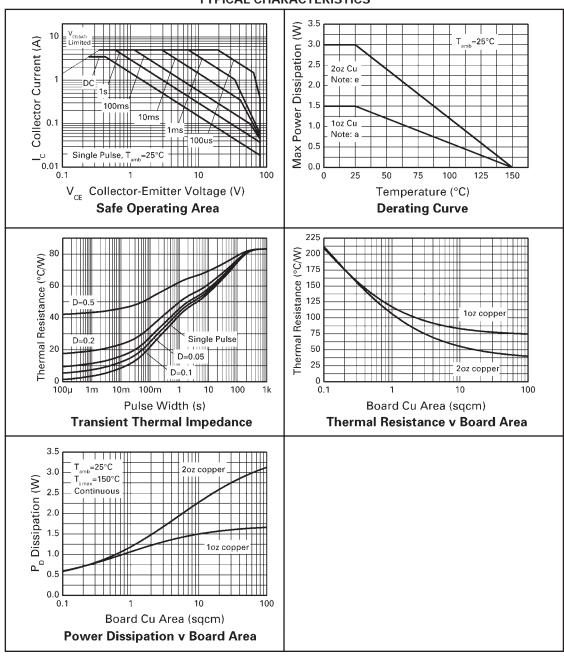
PARAMETER	SYMBOL	VALUE	UNIT				
Junction to Ambient ^(a)	$R_{\Theta JA}$	83	°C/W				
Junction to Ambient ^(b)	$R_{\Theta JA}$	51	°C/W				
Junction to Ambient ^(d)	$R_{\Theta JA}$	125	°C/W				
Junction to Ambient ^(e)	$R_{\Theta JA}$	42	°C/W				

NOTES

- (a) For a single device surface mounted on 10 sq cm 1oz copper on FR4 PCB, in still air conditions with all exposed pads attached.
- (b) For a single device surface mounted on 10 sq cm 1oz copper on FR4 PCB, in still air conditions measured at t≤5 secs with all exposed pads attached.
- $(c) \ Repetitive \ rating pulse \ width \ limited \ by \ max \ junction \ temperature. \ Refer \ to \ Transient \ Thermal \ Impedance \ graph.$
- (d) For a single device surface mounted on 10 sq cm 1oz copper FR4 PCB, in still air conditions with minimal lead connections only.
- (e) For a single device surface mounted on 65 sq cm 2oz copper FR4 PCB, in still air conditions with all exposed pads attached.
- (f) The minimum copper dimensions required for mounting are no smaller than the exposed metal pads on the base of the device, as shown in the package dimensions data. The thermal resistance for a device mounted on 1.5mm thick FR4 board using minimum copper of 1oz weight and 1mm wide tracks is Rth= 300°C/W giving a power rating of Ptot=420mW



TYPICAL CHARACTERISTICS





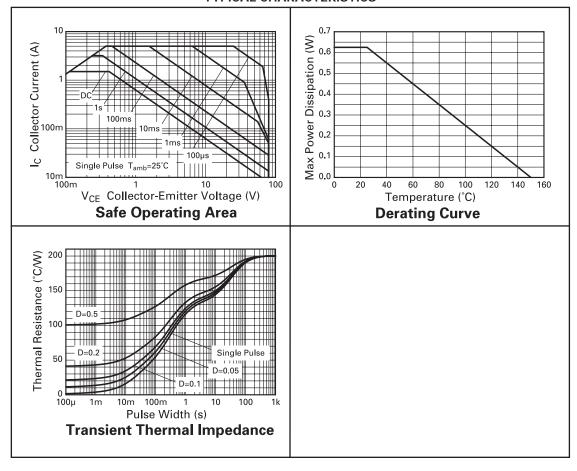
ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25$ °C unless otherwise stated)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS
Collector-Base Breakdown Voltage	V _{(BR)CBO}	100	180		V	I _C =100μA
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	80	110		V	I _C =10mA*
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	7.5	8.2		V	I _E =100μA
Collector Cut-Off Current	I _{CBO}			25	nA	V _{CB} =80V
Emitter Cut-Off Current	I _{EBO}			25	nA	V _{EB} =6V
Collector Emitter Cut-Off Current	I _{CES}			25	nA	V _{CE} =65V
Collector-Emitter Saturation Voltage	V _{CE(sat)}		15 45 145 160 240	20 60 185 200 325	mV mV mV mV	I _C =0.1A, I _B =10mA* I _C =0.5A, I _B =50mA* I _C =1A, I _B =20mA* I _C =1.5A, I _B =50mA* I _C =3.5A, I _B =300mA*
Base-Emitter Saturation Voltage	V _{BE(sat)}		1.09	1.175	V	I _C =3.5A, I _B =300mA*
Base-Emitter Turn-On Voltage	V _{BE(on)}		0.96	1.05	V	I _C =3.5A, V _{CE} =2V*
Static Forward Current Transfer Ratio	h _{FE}	200 300 110 60 20	450 450 170 90 30 10	900		I _C =10mA, V _{CE} =2V* I _C =200mA, V _{CE} =2V* I _C =1A, V _{CE} =2V* I _C =1.5A, V _{CE} =2V* I _C =3A, V _{CE} =2V* I _C =5A, V _{CE} =2V*
Transition Frequency	f _T	100	160		MHz	I _C =50mA, V _{CE} =10V f=100MHz
Output Capacitance	C _{obo}		11.5	18	pF	V _{CB} =10A, f=1MHz
Turn-On Time	t _(on)		86		ns	V _{CC} =10V, I _C =1A
Turn-Off Time	t _(off)		1128		ns	I _{B1} =I _{B2} =25mA

^{*}Measured under pulsed conditions. Pulse width=300 $\mu s.$ Duty cycle $\leq 2\%$

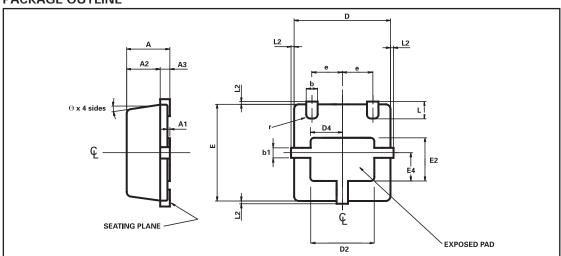


TYPICAL CHARACTERISTICS



ZETEX SEMICONDUCTORS

PACKAGE OUTLINE



Controlling dimensions are in millimetres. Approximate conversions are given in inches

PACKAGE DIMENSIONS

DIM	Millin	netres	Inc	hes	DIM	Millimetres		Inches		
DIIVI	Min	Max	Min	Max	DIIVI	Min	Max	Min	Max	
Α	0.80	1.00	0.0315	0.0393	е	0.65	0.65 REF 2.00 BSC		0.0255 REF	
A1	0.00	0.05	0.00	0.002	Ε	2.00			0.0787 BSC	
A2	0.65	0.75	0.0255	0.0295	E2	0.79	0.99	0.031	0.039	
A3	0.15	0.25	0.0059	0.0098	E4	0.48	0.68	0.0188	0.0267	
b	0.18	0.28	0.0070	0.0110	L	0.20	0.45	0.0078	0.0177	
b1	0.17	0.30	0.0066	0.0118	L2	0.125 MAX.		0.005 REF		
D	2.00	BSC	0.0787 BSC		r	0.075 BSC		0.0029 BSC		
D2	1.22	1.42	0.0480	0.0559	θ	0°	12°	0°	12°	
D4	0.56	0.76	0.0220	0.0299						

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